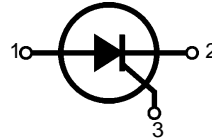
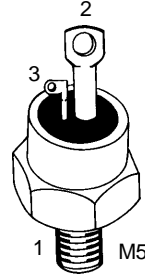


Phase Control Thyristors

$V_{RRM} = 800-1200 \text{ V}$
 $I_{T(RMS)} = 25 \text{ A}$
 $I_{T(AV)M} = 16 \text{ A}$

| V_{RSM} V_{DSM} V | V_{RRM} V_{DRM} V | Type |
|-------------------------------|-------------------------------|------------|
| 900 | 800 | CS 8-08io2 |
| 1300 | 1200 | CS 8-12io2 |


TO-64


1 = Anode, 2 = Cathode, 3 = Gate

| Symbol | Test Conditions | Maximum Ratings | |
|----------------|--|------------------------------------|-----------------------|
| $I_{T(RMS)}$ | $T_{VJ} = T_{VJM}$ | 25 A | |
| $I_{T(AV)M}$ | $T_{case} = 85^{\circ}\text{C}; 180^{\circ}$ sine | 16 A | |
| I_{TSM} | $T_{VJ} = 45^{\circ}\text{C}; V_R = 0$ | t = 10 ms (50 Hz), sine | 250 A |
| | | t = 8.3 ms (60 Hz), sine | 270 A |
| | $T_{VJ} = T_{VJM}; V_R = 0$ | t = 10 ms (50 Hz), sine | 200 A |
| | | t = 8.3 ms (60 Hz), sine | 220 A |
| I^2t | $T_{VJ} = 45^{\circ}\text{C}; V_R = 0$ | t = 10 ms (50 Hz), sine | 310 A ² s |
| | | t = 8.3 ms (60 Hz), sine | 306 A ² s |
| | $T_{VJ} = T_{VJM}; V_R = 0$ | t = 10 ms (50 Hz), sine | 200 A ² s |
| | | t = 8.3 ms (60 Hz), sine | 200 A ² s |
| $(di/dt)_{cr}$ | $T_{VJ} = T_{VJM}; f = 50\text{Hz}; t_p = 200\mu\text{s}; V_D = 2/3 V_{DRM}; I_G = 0.2 \text{ A}; di_G/dt = 0.2 \text{ A}/\mu\text{s}$ | repetitive, $I_T = 48 \text{ A}$ | 150 A/ μs |
| | | non repetitive, $I_T = I_{T(AV)M}$ | 500 A/ μs |
| $(dv/dt)_{cr}$ | $T_{VJ} = T_{VJM}; R_{GK} = \infty; \text{method 1 (linear voltage rise)}$ | $V_{DR} = 2/3 V_{DRM}$ | 1000 V/ μs |
| P_{GM} | $T_{VJ} = T_{VJM}; I_T = I_{T(AV)M}$ | $t_p = 30 \mu\text{s}$ | 10 W |
| | | $t_p = 300 \mu\text{s}$ | 5 W |
| $P_{G(AV)}$ | | | 0.5 W |
| V_{RGM} | | | 10 V |
| T_{VJ} | | -40...+125 | $^{\circ}\text{C}$ |
| T_{VJM} | | 125 | $^{\circ}\text{C}$ |
| T_{stg} | | -40...+125 | $^{\circ}\text{C}$ |
| M_d | Mounting torque | | 2.5 Nm |
| | | | 22 lb.in. |
| Weight | | | 6 g |

Features

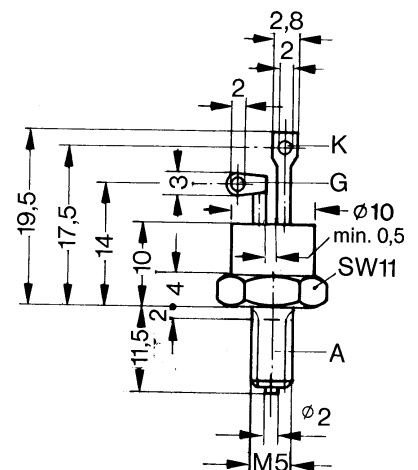
- Thyristor for line frequencies
- International standard package JEDEC TO-64
- Planar glassivated chip
- Long-term stability of blocking currents and voltages

Applications

- Motor control
- Power converter
- AC power controller

Advantages

- Space and weight savings
- Simple mounting
- Improved temperature and power cycling

Dimensions in mm (1 mm = 0.0394")


Data according to IEC 60747
 IXYS reserves the right to change limits, test conditions and dimensions

| Symbol | Test Conditions | Characteristic Values | |
|------------|--|-----------------------|---------------------|
| I_R, I_D | $T_{VJ} = T_{VJM}; V_R = V_{RRM}; V_D = V_{DRM}$ | \leq | 3 mA |
| V_T | $I_T = 33 \text{ A}; T_{VJ} = 25^\circ\text{C}$ | \leq | 1.6 V |
| V_{T0} | For power-loss calculations only ($T_{VJ} = 125^\circ\text{C}$) | | 1.0 V |
| r_T | | | 18 m Ω |
| V_{GT} | $V_D = 6 \text{ V}; T_{VJ} = 25^\circ\text{C}$ | \leq | 2.5 V |
| | $T_{VJ} = -40^\circ\text{C}$ | \leq | 3.5 V |
| I_{GT} | $V_D = 6 \text{ V}; T_{VJ} = 25^\circ\text{C}$ | \leq | 30 mA |
| | $T_{VJ} = -40^\circ\text{C}$ | \leq | 50 mA |
| V_{GD} | $T_{VJ} = T_{VJM}; V_D = 2/3 V_{DRM}$ | \leq | 0.2 V |
| I_{GD} | | \leq | 1 mA |
| I_L | $T_{VJ} = 25^\circ\text{C}; t_p = 10 \mu\text{s}$ $I_G = 0.09 \text{ A}; di_G/dt = 0.09 \text{ A}/\mu\text{s}$ | \leq | 100 mA |
| I_H | $T_{VJ} = 25^\circ\text{C}; V_D = 6 \text{ V}; R_{GK} = \infty$ | \leq | 80 mA |
| t_{gd} | $T_{VJ} = 25^\circ\text{C}; V_D = 1/2 V_{DRM}$ $I_G = 0.09 \text{ A}; di_G/dt = 0.09 \text{ A}/\mu\text{s}$ | \leq | 2 μs |
| t_q | $T_{VJ} = T_{VJM}; I_T = 16 \text{ A}, t_p = 300 \mu\text{s}; di/dt = -20 \text{ A}/\mu\text{s}$ $V_R = 100 \text{ V}; dv/dt = 20 \text{ V}/\mu\text{s}; V_D = 2/3 V_{DRM}$ | typ. | 60 μs |
| R_{thJC} | DC current | | 1.5 K/W |
| R_{thJH} | DC current | | 2.5 K/W |
| d_s | Creepage distance on surface | | 1.55 mm |
| d_A | Strike distance through air | | 1.55 mm |
| a | Max. acceleration, 50 Hz | | 50 m/s ² |

Accessories:

Nut M5 DIN 439/SW8

Lock washer A5 DIN 128

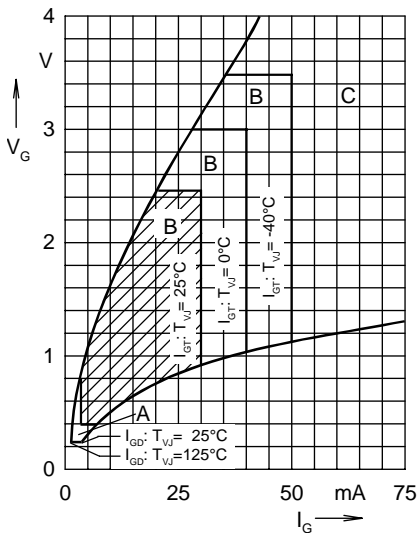


Fig. 1 Gate voltage and gate current Triggering:
A = no; B = possible; C = safe

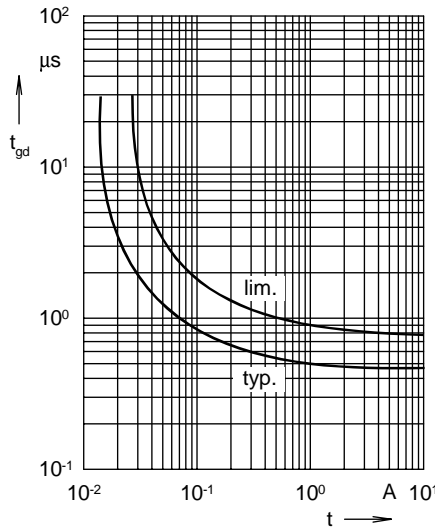


Fig. 2 Gate controlled delay time t_{gd}

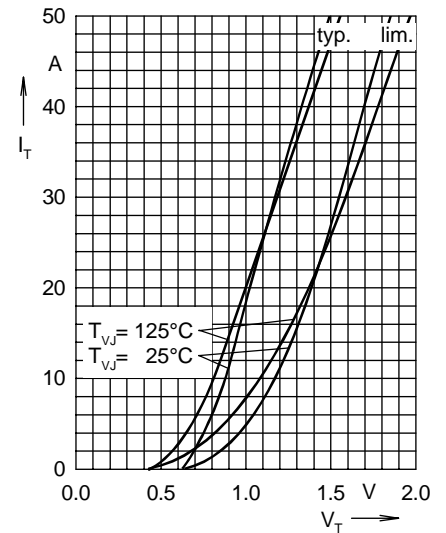


Fig. 3 On-state characteristics

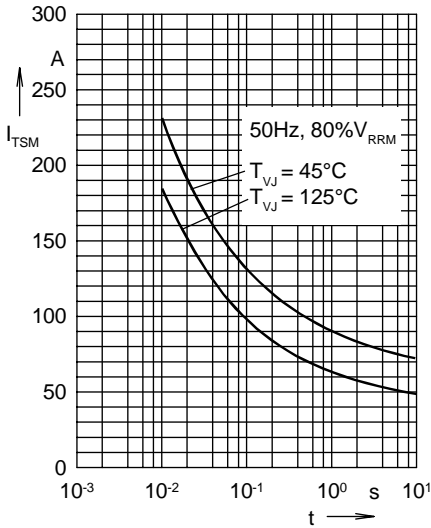


Fig. 4 Surge overload current
 I_{TSM} : crest value, t: duration

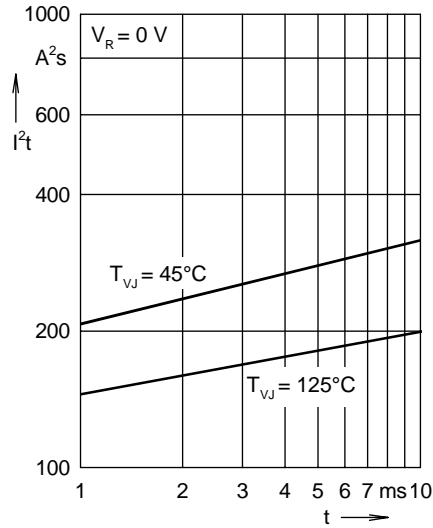


Fig. 5 I^2t versus time (1-10 ms)

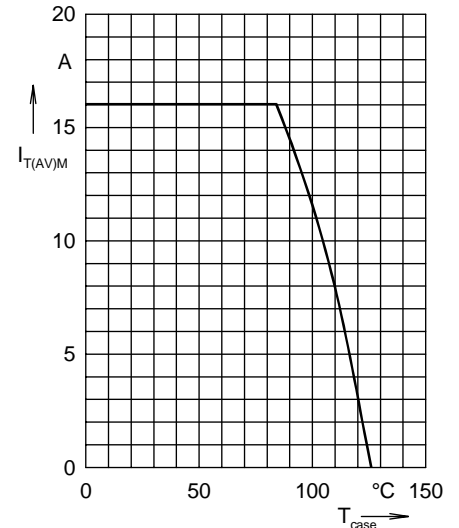


Fig. 6 Maximum forward current at case temperature 180° sine

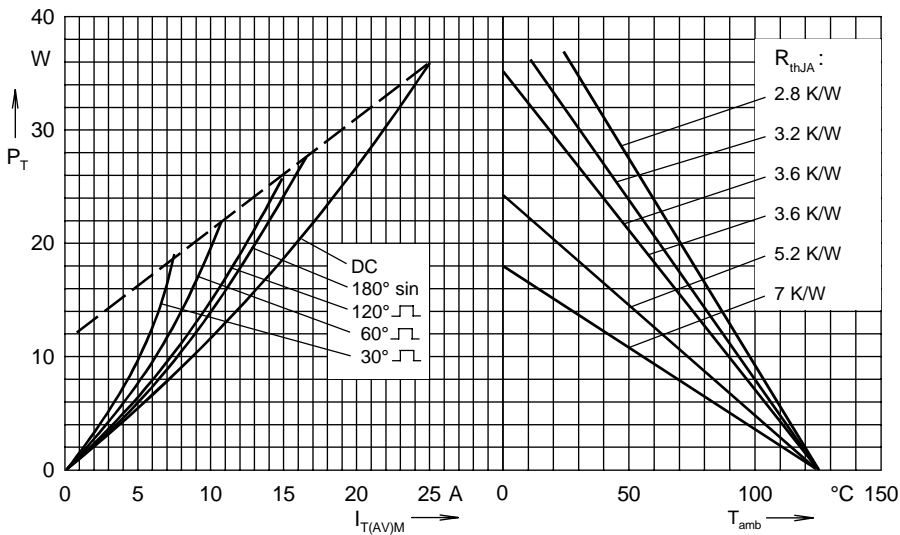


Fig. 7 Power dissipation versus on-state current and ambient temperature

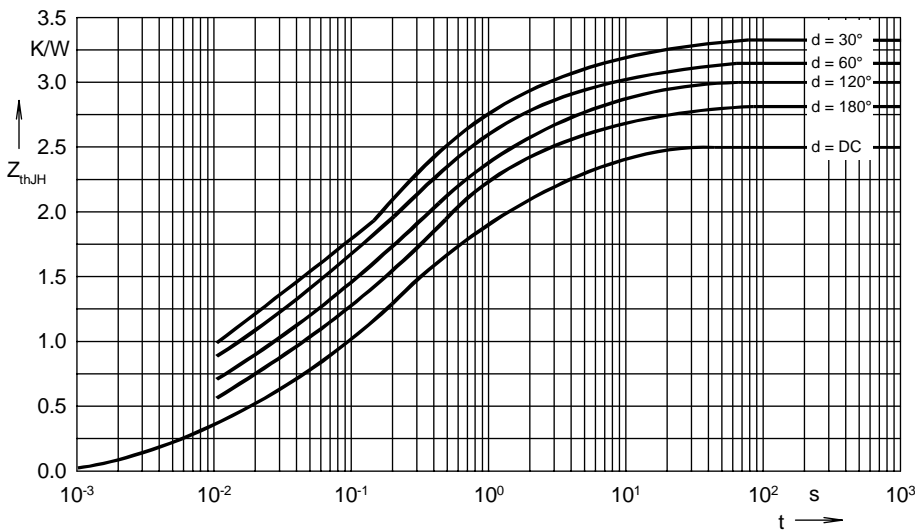


Fig. 8 Transient thermal impedance junction to heatsink

R_{thJH} for various conduction angles d:

| d | R_{thJH} (K/W) |
|------|------------------|
| DC | 2.5 |
| 180° | 2.79 |
| 120° | 2.95 |
| 60° | 3.17 |
| 30° | 3.32 |

Constants for Z_{thJH} calculation:

| i | R_{thi} (K/W) | t_i (s) |
|---|-----------------|-----------|
| 1 | 0.252 | 0.005 |
| 2 | 0.333 | 0.0225 |
| 3 | 0.5 | 0.145 |
| 4 | 0.833 | 0.43 |
| 5 | 0.416 | 2.75 |
| 6 | 0.166 | 23 |